

Title (en)

III-NITRIDE STRUCTURES GROWN SILICON SUBSTRATES WITH INCREASED COMPRESSIVE STRESS

Title (de)

AUF SILICIUMSUBSTRATEN GEZÜCHTETE III-NITRID-STRUKTUREN MIT ERHÖHTER DRUCKEIGENSCHENSPANNUNG

Title (fr)

SUBSTRATS EN SILICIUM OBTENUS PAR CROISSANCE AVEC STRUCTURES AU NITRURE III PRÉSENTANT UNE CONTRAINTE DE COMPRESSION ACCRUE

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Application

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